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| APPLICATION NO. | F | ILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|-------------------------------------|----------|------------|----------------------|-------------------------|------------------|
| 10/830,120 | | 04/23/2004 | Jung-hyun Lee | 249/456 | 9015 |
| 27849 | 7590 | 04/05/2006 | | EXAMINER | |
| LEE & MC | RSE, P.O | C. | STARK, JARRETT J | | |
| 1101 WILSON BOULEVARD SUITE 2000 | | | | ART UNIT | PAPER NUMBER |
| ARLINGTON, VA 22209 | | | | 2823 | |
| | | | | DATE MAILED: 04/05/2000 | 5 |

Please find below and/or attached an Office communication concerning this application or proceeding.

| | | I A II | | | | | |
|---|--|--|---|--|--|--|--|
| | Application No. | Applicant(s) | | | | | |
| | 10/830,120 | LEE ET AL. | | | | | |
| Office Action Summary | Examiner | Art Unit | | | | | |
| | Jarrett J. Stark | 2823 | | | | | |
| The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply | | | | | | | |
| A SHORTENED STATUTORY PERIOD FO WHICHEVER IS LONGER, FROM THE MA - Extensions of time may be available under the provisions of after SIX (6) MONTHS from the mailing date of this commun- If NO period for reply is specified above, the maximum statu- Failure to reply within the set or extended period for reply widen and the period patent term adjustment. See 37 CFR 1.704(b). | ILING DATE OF THIS COMMUN 37 CFR 1.136(a). In no event, however, may nication. Itory period will apply and will expire SIX (6) Mi ill, by statute, cause the application to become | IICATION. a reply be timely filed DNTHS from the mailing date of this communication. ABANDONED (35 U.S.C. § 133). | | | | | |
| Status | | | | | | | |
| 1) Responsive to communication(s) filed | on <u>23 April 2004</u> . | | | | | | |
| 2a) This action is FINAL . 2b | This action is FINAL . 2b)⊠ This action is non-final. | | | | | | |
| • | Since this application is in condition for allowance except for formal matters, prosecution as to the merits is | | | | | | |
| closed in accordance with the practice | e under <i>Ex parte Quayle</i> , 1935 C | .D. 11, 453 O.G. 213. | | | | | |
| Disposition of Claims | | | | | | | |
| 4) ⊠ Claim(s) 1-11 is/are pending in the ap 4a) Of the above claim(s) is/are 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) 1-11 is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction | withdrawn from consideration. | | • | | | | |
| Application Papers | | · | | | | | |
| 9) The specification is objected to by the | Examiner. | | | | | | |
| 10)⊠ The drawing(s) filed on <u>23 April 2004</u> is/are: a) accepted or b)⊠ objected to by the Examiner. | | | | | | | |
| Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). | | | | | | | |
| Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). | | | | | | | |
| 11)☐ The oath or declaration is objected to I | by the Examiner. Note the attach | ed Office Action or form PTO-152. | | | | | |
| Priority under 35 U.S.C. § 119 | | | | | | | |
| 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. | | | | | | | |
| Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PT 3) Information Disclosure Statement(s) (PTO-1449 or P Paper No(s)/Mail Date 23 April 2004. | O-948) Paper N | v Summary (PTO-413) o(s)/Mail Date if Informal Patent Application (PTO-152) | | | | | |

DETAILED ACTION

Election/Restrictions

Applicant's election without traverse of Group I, Claims 1-11 in the reply filed on 3/13/2006 is acknowledged.

Drawings

Figures 1-3E, as described in applicant's disclosure paragraphs [0003]-[0020], should be designated by a legend such as --Prior Art-- because only that which is old is illustrated. See MPEP § 608.02(g). Corrected drawings in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. The replacement sheet(s) should be labeled "Replacement Sheet" in the page header (as per 37 CFR 1.84(c)) so as not to obstruct any portion of the drawing figures. If the changes are not accepted by the examiner, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

Application/Control Number: 10/830,120

Art Unit: 2823

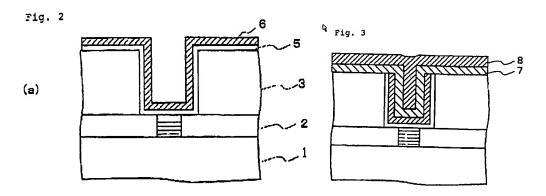
A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1 and 5 are rejected under 35 U.S.C. 102(b) as being anticipated by Aoki et al. (US 2002/0072191).

Regarding claim 1, Aoki et al. discloses a stack-type capacitor comprising: a lower electrode; (Aoki et al, Fig. 2 ref #'s 5&6) a dielectric layer formed on the lower electrode; (Aoki et al, Fig. 2 ref # 7) and an upper electrode formed on the dielectric layer, (Aoki et al, Fig. 3 ref # 8) wherein the lower electrode includes:

a first metal layer having a cylindrical shape; and (Aoki et al, Fig. 2 ref # 5) a second metal layer filled in the first metal layer. (Aoki et al, Fig. 2 ref # 6)



Regarding claim 5, Aoki et al. discloses a semiconductor memory device including a stack-type capacitor, the device comprising a transistor and a capacitor, wherein the capacitor includes: (Aoki et al, paragraph [0032])

a lower electrode; (Aoki et al, Fig. 2 ref #'s 5&6)

Application/Control Number: 10/830,120

Art Unit: 2823

a dielectric layer formed on the lower electrode; (Aoki et al, Fig. 2 ref # 7) and an upper electrode formed on the dielectric layer, (Aoki et al, Fig. 3 ref # 8) wherein the lower electrode includes:

a first metal layer having a cylindrical shape; and (Aoki et al, Fig. 2 ref # 5) a second metal layer filled in the first metal layer. (Aoki et al, Fig. 2 ref # 6)

Regarding claim 6, Aoki et al. discloses the device as claimed in claim 5, wherein the transistor is electrically connected to the capacitor by a conductive plug. (Aoki et al, paragraph [0032])

Regarding claims 7 & 8, Aoki et al. discloses the device as claimed in claim 6, wherein a diffusion barrier layer is formed between the lower electrode and the conductive plug. (Aoki et al, paragraph [0032])

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 2-4 and 9-11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Aoki et al. (US 2002/0072191) in view of <u>Kim et al.</u> (US 2001/00544730).

Application/Control Number: 10/830,120

Art Unit: 2823

Regarding claims 2 & 9, Aoki discloses the capacitor as claimed in claim 1 & 5.

Aoki does not expressly disclose wherein the first metal layer is a ruthenium layer and the second metal layer is a nitride and aluminum layer.

<u>Kim</u> discloses wherein the metal layers of the capacitor can be formed from Ru and TaAIN. (<u>Kim</u>, paragraph [0013])

The two references are analogous art because they are from the same field of endeavor of forming a cylindrical stack type capacitor.

At the time of the invention, it would have been obvious to a person of ordinary skill in the art to use Ru and TaAlN to form the metal layers of the stack capacitor.

Therefore, it would have been obvious to combine <u>Kim</u> with <u>Aoki</u> to obtain the invention as specified.

lower electrode in a capacitor according to the embodiment of the present invention is formed of a refractory metal such as Ti, Ta and W or a refractory metal compound such as TiN, TiSiN, TiAlN, TaN, TaSiN, TaAlN and WN. In particular, when the lower electrode 10 has a three-dimensional structure such as a cylindrical shape, a refractory metal or refractory metal compound deposited by CVD or ALD providing good step coverage is preferable. (Kim, paragraph [0031])

Regarding claim 3 & 10, Aoki in view of Kim disclose the capacitor as claimed in claim 2 & 9, wherein the nitride and aluminum layer is a titanium aluminum nitride layer or a tantalum aluminum nitride layer. (Kim, paragraph [0031])

Art Unit: 2823

Regarding claim 4 & 11, Aoki in view of Kim disclose the capacitor as claimed in claim 2 & 9, wherein the upper electrode is a ruthenium layer. (Kim, paragraph [0013])

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jarrett J. Stark whose telephone number is (571) 272-6005. The examiner can normally be reached on Monday - Thursday 7:00AM - 5:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith can be reached on (571) 272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

JJS March 20, 2006

W. DAVID COLEMAN PRIMARY EXAMINER

Page 6